February 1992 Revised June 2001

74LVQ02 Low Voltage Quad 2-Input NOR Gate

General Description

FAIRCHILD

SEMICONDUCTOR

The LVQ02 contains four 2-input NOR gates.

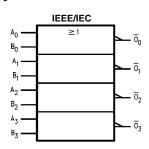
Features

- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- **G**uaranteed incident wave switching into 75Ω

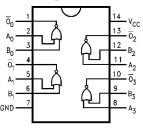
Ordering Code:

| - | | | | | | |
|---|----------------|--|--|--|--|--|
| Order Number | Package Number | Package Description | | | | |
| 74LVQ02SC | M14A | 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow | | | | |
| 74LVQ02SJ M14D 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide | | | | | | |
| Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. | | | | | | |

Logic Symbol



Connection Diagram



Pin Descriptions

| Pin Names | Description | | | |
|---------------------------------|-------------|--|--|--|
| A _n , B _n | Inputs | | | |
| Ōn | Outputs | | | |

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Absolute Maximum Ratings(Note 1)

| Supply Voltage (V _{CC}) | -0.5V to +7.0V | Condition |
|--|----------------------------|--|
| DC Input Diode Current (I _{IK}) | | Supply Voltage |
| $V_{I} = -0.5V$ | –20 mA | LVQ |
| $V_I = V_{CC} + 0.5V$ | +20 mA | Input Voltage (V |
| DC Input Voltage (VI) | $-0.5V$ to $V_{CC} + 0.5V$ | Output Voltage |
| DC Output Diode Current (I _{OK}) | | Operating Temp |
| $V_0 = -0.5V$ | –20 mA | 74LVQ |
| $V_O = V_{CC} + 0.5V$ | +20 mA | Minimum Input |
| DC Output Voltage (V _O) | $-0.5V$ to $V_{CC} + 0.5V$ | V _{IN} from 0.8V |
| DC Output Source | | V _{CC} @ 3.0V |
| or Sink Current (I _O) | ±50 mA | Note 1: The "Absolute |
| DC V _{CC} or Ground Current | | the safety of the devic operated at these lim |
| (I _{CC} or I _{GND}) | ±200 mA | Characteristics tables The "Recommended 0 |
| Storage Temperature (T _{STG}) | -65°C to +150°C | for actual device opera |
| DC Latch-Up Source or | | Note 2: Unused inputs |
| Sink Current | ±100 mA | |

Recommended Operating Conditions (Note 2)

| Supply Voltage (V _{CC}) | |
|---|----------------------------------|
| LVQ | 2.0V to 3.6V |
| Input Voltage (V _I) | 0V to V _{CC} |
| Output Voltage (V _O) | 0V to V _{CC} |
| Operating Temperature (T _A) | |
| 74LVQ | $-40^{\circ}C$ to $+85^{\circ}C$ |
| Minimum Input Edge Rate ($\Delta V/\Delta t$) | |
| V _{IN} from 0.8V to 2.0V | |
| V _{CC} @ 3.0V | 125 mV/ns |
| Note 1: The "Absolute Maximum Ratings" are the | |

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

| Symbol | Parameter | v _{cc} | $T_A = +25^{\circ}C$ | | $\textbf{T}_{\textbf{A}}=-40^{\circ}\textbf{C}$ to $+85^{\circ}\textbf{C}$ | Units | Conditions | |
|------------------|---|-----------------|----------------------|------|--|-------|---|--|
| | | (V) | Тур | Gua | aranteed Limits | | | |
| V _{IH} | Minimum High Level Input Voltage | 3.0 | 1.5 | 2.0 | 2.0 | V | $V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$ | |
| V _{IL} | Maximum Low Level Input Voltage | 3.0 | 1.5 | 0.8 | 0.8 | V | $V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$ | |
| V _{OH} | Minimum High Level | 3.0 | 2.99 | 2.9 | 2.9 | V | I _{OUT} = -50 μA | |
| | Output Voltage | 3.0 | | 2.58 | 2.48 | V | $V_{IN} = V_{IL}$ or V_{IH} (Note 3) $I_{OH} = -12 \text{ mA}$ | |
| V _{OL} | Maximum Low Level | 3.0 | 0.002 | 0.1 | 0.1 | V | $I_{OUT} = 50 \ \mu A$ | |
| | Output Voltage | 3.0 | | 0.36 | 0.44 | V | $V_{IN} = V_{IL} \text{ or } V_{IH} \text{ (Note 3)}$ $I_{OL} = 12 \text{ mA}$ | |
| I _{IN} | Maximum Input Leakage Current | 3.6 | | ±0.1 | ±1.0 | μΑ | $V_I = V_{CC}, GND$ | |
| I _{OLD} | Minimum Dynamic (Note 4) | 3.6 | | | 36 | mA | V _{OLD} = 0.8V Max (Note 5) | |
| I _{OHD} | Output Current | 3.6 | | | -25 | mA | V _{OHD} = 2.0V Min (Note 5) | |
| I _{CC} | Maximum Quiescent Supply Current | 3.6 | | 2.0 | 20.0 | μΑ | V _{IN} = V _{CC} or GND | |
| V _{OLP} | Quiet Output Maximum Dynamic V _{OL} | 3.3 | 0.6 | 1.0 | | V | (Note 6)(Note 7) | |
| V _{OLV} | Quiet Output Minimum Dynamic V _{OL} | 3.3 | -0.7 | -1.0 | | V | (Note 6)(Note 7) | |
| V _{IHD} | Maximum High Level Dynamic Input Voltage | 3.3 | 1.7 | 2.0 | | V | (Note 6)(Note 8) | |
| V _{ILD} | Maximum Low Level Dynamic Input Voltage | 3.3 | 1.7 | 0.8 | | V | (Note 6)(Note 8) | |

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n - 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

| AC E | lectrical Characterist | ics | | | | | | | |
|--------------------|--------------------------------|-----------------|-----------------------|----------------------|------|-----------------------|------------|-------|--|
| | | | | $T_A = +25^{\circ}C$ | | T _A = -40° | C to +85°C | | |
| Symbol | Parameter | v _{cc} | $C_L = 50 \text{ pF}$ | | | $C_L = 50 \text{ pF}$ | | Units | |
| | | (V) | Min | Тур | Max | Min | Max | | |
| t _{PLH} | Propagation Delay | 2.7 | 1.5 | 6.0 | 10.6 | 1.0 | 12.0 | | |
| | | 3.3 ± 0.3 | 1.5 | 5.0 | 7.5 | 1.0 | 8.0 | ns | |
| t _{PHL} | Propagation Delay | 2.7 | 1.5 | 6.0 | 10.6 | 1.0 | 12.0 | | |
| | | 3.3 ± 0.3 | 1.5 | 5.0 | 7.5 | 1.0 | 8.0 | ns | |
| t _{OSHL,} | Output to Output Skew (Note 9) | 2.7 | | 1.0 | 1.5 | | 1.5 | | |
| tOSLH | Data to Output | 3.3 ± 0.3 | | 1.0 | 1.5 | | 1.5 | ns | |

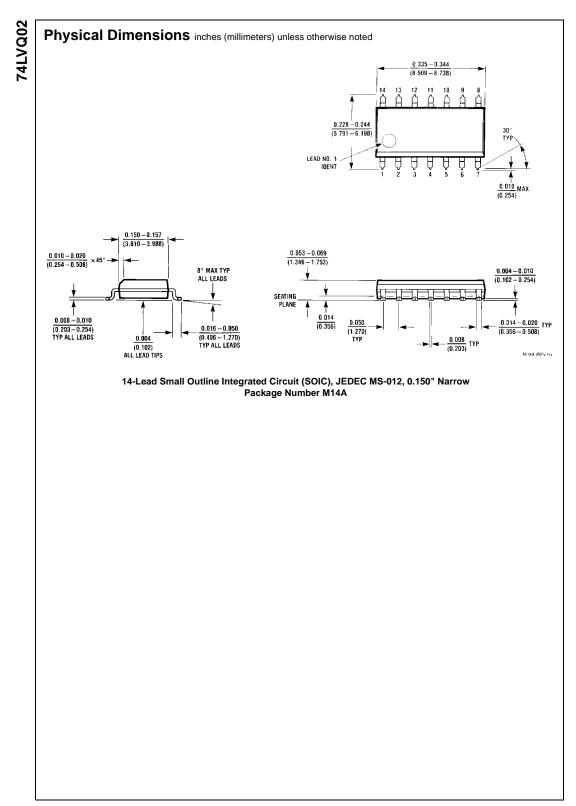
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

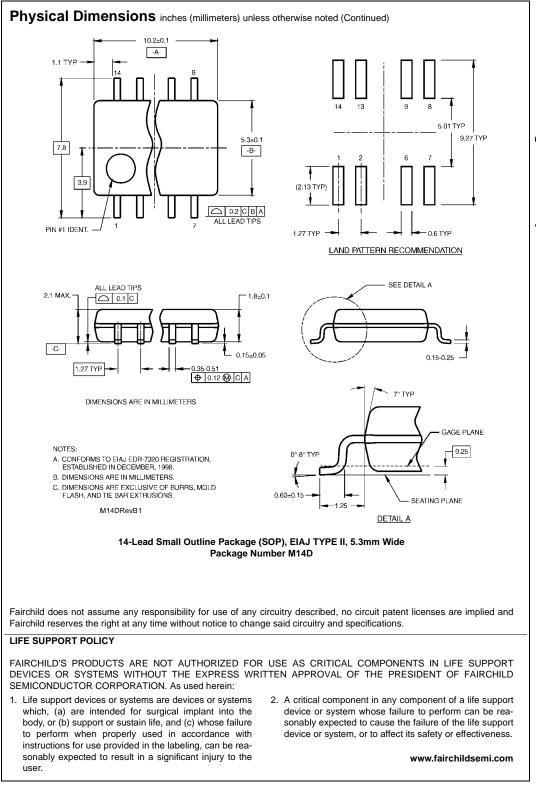
Capacitance

| Symbol | Parameter | Тур | Units | Conditions |
|---------------------------|-------------------------------|-----|-------|------------------------|
| C _{IN} | Input Capacitance | 4.5 | pF | V _{CC} = Open |
| C _{PD} (Note 10) | Power Dissipation Capacitance | 20 | pF | V _{CC} = 3.3V |

Note 10: C_{PD} is measured at 10 MHz.

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